SN74LXC1T45-Q1 車載用シングル・ビット、デュアル電源バス・トランシーバ、構成可能なレベル・シフト機能付き

1 特長

- 完全に構成可能なデュアル・レール設計により、各ポートは 1.1V～5.5V で動作可能
- 堅牢でグリッチの発生しない電源シーケンシング
- 3.3V～5.0V で最高 420Mbps をサポート
- シュミット・トリガ入力により低速またはノイズの多い入力に対応
- ダイナミック・プルダウン抵抗を内蔵した I/O により、外付け部品数の削減が可能
- スタティック・プルダウン抵抗を内蔵した制御入力により、制御入力のフローティングが可能
- 高い駆動強度 (5V で最大 32mA)
- 低い消費電力
  - 最大 3µA (25℃)
  - 最大 6µA (-40℃～125℃)
- V_{CC} 絶縁および V_{CC} 切断 ($I_{off-float}$) 機能
  - どちらかの V_{CC} 電源が 100mV 未満になった場合または切断された場合、すべての I/O がプルダウンされた後に高インピーダンス状態に移行
- I_{off} により部分的パワーダウン・モードでの動作をサポート
- LVC ファミリのレベル・シフタと互換
- 制御ロジック (DIR および $\overline{OE}$) は V_{CCA} 基準
- 動作温度範囲:-40℃～+125℃
- JESD 78、Class II 準拠で 100mA 超のラッチアップ性能
- JESD 22 を上回る ESD 保護
  - 人体モデル 4000V
  - デバイス帯電モデル 1000V

2 アプリケーション

- 低速またはノイズの多い入力信号の除去
- インジケータ LED または ブザーの駆動
- メカニカルスイッチのデバウンス
- 汎用 I/O レベル・シフト

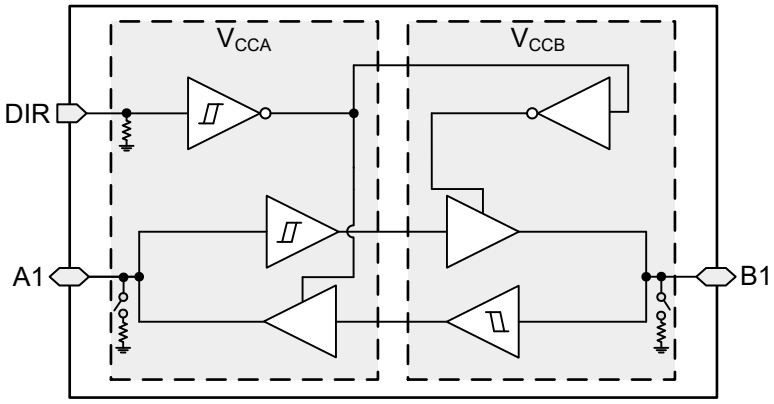
3 概要

SN74LXC1T45-Q1 は、1 ビット、デュアル電源、非反転双方向電圧レベル変換デバイスです。I/O ピン A および制御ピン (DIR) は V_{CCA} のロジック・レベルを基準とし、I/O ピン B は V_{CCB} ロジック・レベルを基準とします。A ポートは 1.1V～5.5V の範囲の I/O 電圧を受け入れ、B ポートは 1.1V～5.5V の I/O 電圧を受け入れます。DIR が HIGH のときは A から B へ、DIR が LOW のときは B から A へデータが転送されます。制御ロジックの概要についてはデバイスの機能モードを参照してください。

パッケージ情報 (1)

部品番号	パッケージ	本体サイズ (公称)
SN74LXC1T45-Q1	SOT (DRL) (6)	1.60mm × 1.20mm
	SON (DRY) (6)	1.45mm × 1.00mm
	SC70 (DCK) (6)	2.00mm × 1.25mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。



SN74LXC1T45-Q1 のブロック図

英語版の TI 製品についての情報を翻訳したこの資料は、製品の概要を確認する目的で便宜的に提供しているものです。該当する正式な英語版の最新情報は、www.ti.com で閲覧でき、その内容が常に優先されます。TI では翻訳の正確性および妥当性につきましては一切保証いたしません。実際の設計などの前には、必ず最新版の英語版をご参照くださいますようお願いいたします。

Table of Contents

1 特長 ... 1
2 アプリケーション ... 1
3 概要 ... 1
4 Revision History ... 2
5 Pin Configuration and Functions ... 3
6 Specifications ... 4
6.1 Absolute Maximum Ratings ... 4
6.2 ESD Ratings ... 4
6.3 Recommended Operating Conditions ... 5
6.4 Thermal Information ... 5
6.5 Electrical Characteristics ... 6
6.6 Switching Characteristics, V_{CCA} = 1.2 ± 0.1 V ... 9
6.7 Switching Characteristics, V_{CCA} = 1.5 ± 0.1 V ... 10
6.8 Switching Characteristics, V_{CCA} = 1.8 ± 0.15 V ... 11
6.9 Switching Characteristics, V_{CCA} = 2.5 ± 0.2 V ... 12
6.10 Switching Characteristics, V_{CCA} = 3.3 ± 0.3 V ... 13
6.11 Switching Characteristics, V_{CCA} = 5.0 ± 0.5 V ... 14
6.12 Switching Characteristics: T_{sk}, T_{MAX} ... 15
6.13 Operating Characteristics ... 15
6.14 Typical Characteristics ... 16
7 Parameter Measurement Information ... 17
7.1 Load Circuit and Voltage Waveforms ... 17
8 Detailed Description ... 19
8.1 Overview ... 19
8.2 Functional Block Diagram ... 19
8.3 Feature Description ... 19
8.4 Device Functional Modes ... 22
9 Application and Implementation ... 23
9.1 Application Information ... 23
9.2 Enable Times ... 23
9.3 Typical Application ... 23
10 Power Supply Recommendations ... 24
11 Layout ... 24
11.1 Layout Guidelines ... 24
11.2 Layout Example ... 24
12 Device and Documentation Support ... 25
12.1 Device Support ... 25
12.2 Documentation Support ... 25
12.3 Receiving Notification of Documentation Updates ... 25
12.4 サポート・リソース ... 25
12.5 Trademarks ... 25
12.6 Electrostatic Discharge Caution ... 25
12.7 Glossary ... 25
13 Mechanical, Packaging, and Orderable Information ... 25

4 Revision History

DATE	REVISION	NOTES
August 2022	*	Initial Release

Copyright © 2022 Texas Instruments Incorporated

5 Pin Configuration and Functions

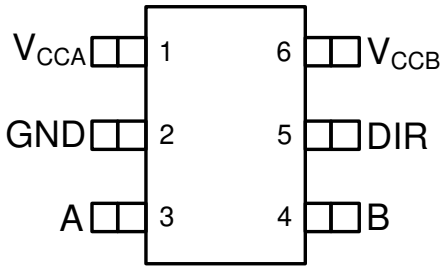


図 5-1. DCK Package, 6-Pin SC70 (Top View)

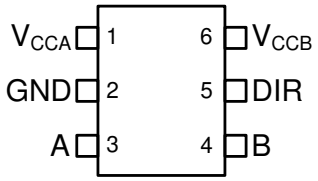


図 5-2. DRL Package Preview, 6-Pin SOT (Top View)

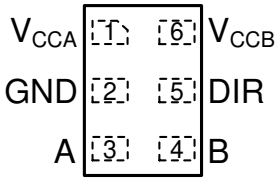


図 5-3. DRY Package Preview, 6-Pin SON (Top View)

表 5-1. Pin Functions

PIN		TYPE(1)	DESCRIPTION
NAME	NO.		
V_{CCA}	1	—	A-port supply voltage. 1.1 V ≤ V_{CCA} ≤ 5.5 V.
GND	2	—	Ground.
A	3	I/O	Input or output A. Referenced to V_{CCA}.
B	4	I/O	Input or output B. Referenced to V_{CCB}.
DIR	5	I	Direction-control signal for all ports. Referenced to V_{CCA}.
V_{CCB}	6	—	B-port supply voltage. 1.1 V ≤ V_{CCB} ≤ 5.5 V.

(1) I = Input, O = Output, GND = ground

Copyright © 2022 Texas Instruments Incorporated

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CCA}	Supply voltage A		–0.5	6.5	V
V_{CCB}	Supply voltage B		–0.5	6.5	V
V_I	Input Voltage(2)	I/O Ports (A Port)	–0.5	6.5	V
		I/O Ports (B Port)	–0.5	6.5	
		Control Inputs	–0.5	6.5	
V_O	Voltage applied to any output in the high-impedance or power-off state(2)	A Port	–0.5	6.5	V
		B Port	–0.5	6.5	
V_O	Voltage applied to any output in the high or low state(2) (3)	A Port	–0.5	V_{CCA} + 0.5	V
		B Port	–0.5	V_{CCB} + 0.5	
I_{IK}	Input clamp current	V_I < 0	–50		mA
I_{OK}	Output clamp current	V_O < 0	–50		mA
I_O	Continuous output current		–50	50	mA
	Continuous current through V_{CC} or GND		–200	200	mA
T_j	Junction Temperature			150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions.* If briefly ooperating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, this device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002(1)	±4000	V
		Charged device model (CDM), per AEC Q100-011	±1000	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification

Copyright © 2022 Texas Instruments Incorporated

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (1) (2) (3)

			MIN	MAX	UNIT
V_{CCA}	Supply voltage A		1.1	5.5	V
V_{CCB}	Supply voltage B		1.1	5.5	V
I_{OH}	High-level output current	V_{CCO} = 1.1 V		–0.1	mA
		V_{CCO} = 1.4 V		–4	
		V_{CCO} = 1.65 V		–8	
		V_{CCO} = 2.3 V		–12	
		V_{CCO} = 3 V		–24	
		V_{CCO} = 4.5 V		–32	
I_{OL}	Low-level output current	V_{CCO} = 1.1 V		0.1	mA
		V_{CCO} = 1.4 V		4	
		V_{CCO} = 1.65 V		8	
		V_{CCO} = 2.3 V		12	
		V_{CCO} = 3 V		24	
		V_{CCO} = 4.5 V		32	
V_I	Input voltage (3)		0	5.5	V
V_O	Output voltage	Active State	0	V_{CCO}	V
		Tri-State	0	5.5	
T_A	Operating free-air temperature		–40	125	°C

(1) V_{CCI} is the V_{CC} associated with the input port.
(2) V_{CCO} is the V_{CC} associated with the output port.
(3) All control inputs and data I/Os of this device have weak pulldowns to ensure the line is not floating when undefined external to the device. The input leakage from these weak pulldowns is defined by the I_I specification indicated under *Electrical Characteristics*.

6.4 Thermal Information

THERMAL METRIC(1)		SN74LXC1T45-Q1			UNIT
		DCK (SC70)	DRL (SOT)	DRY (SON)	
		6 PINS	6 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	216.1	TBD	293.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	143.6	TBD	184.0	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	75.9	TBD	164.9	°C/W
Y_{JT}	Junction-to-top characterization parameter	58.5	TBD	28.3	°C/W
Y_{JB}	Junction-to-board characterization parameter	75.6	TBD	164.0	°C/W
$R_{\theta JC(bottom)}$	Junction-to-case (bottom) thermal resistance	N/A	TBD	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

Copyright © 2022 Texas Instruments Incorporated

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)(1) (2)

PARAMETER		TEST CONDITIONS	V_{CCA}	V_{CCB}	Operating free-air temperature (T_A)									UNIT
					25°C			–40°C to 85°C			–40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{T+}	Positive-going input-threshold voltage	Data Inputs (Ax, Bx) (Referenced to V_{CCI})	1.1 V	1.1 V				0.44		0.88	0.44		0.88	V
			1.4 V	1.4 V				0.60		0.98	0.60		0.98	
			1.65 V	1.65 V				0.76		1.13	0.76		1.13	
			2.3 V	2.3 V				1.08		1.56	1.08		1.56	
			3 V	3 V				1.48		1.92	1.48		1.92	
			4.5 V	4.5 V				2.19		2.74	2.19		2.74	
			5.5 V	5.5 V				2.65		3.33	2.65		3.33	
		Control Input (DIR) (Referenced to V_{CCA})	1.1 V	1.1 V				0.44		0.88	0.44		0.88	V
			1.4 V	1.4 V				0.60		0.98	0.60		0.98	
			1.65 V	1.65 V				0.76		1.13	0.76		1.13	
			2.3 V	2.3 V				1.08		1.56	1.08		1.56	
			3 V	3 V				1.48		1.92	1.48		1.92	
			4.5 V	4.5 V				2.19		2.74	2.19		2.74	
			5.5 V	5.5 V				2.65		3.33	2.65		3.33	
V_{T-}	Negative-going input-threshold voltage	Data Inputs (Ax, Bx) (Referenced to V_{CCI})	1.1 V	1.1 V				0.17		0.48	0.17		0.48	V
			1.4 V	1.4 V				0.28		0.59	0.28		0.59	
			1.65 V	1.65 V				0.35		0.69	0.35		0.69	
			2.3 V	2.3 V				0.56		0.97	0.56		0.97	
			3 V	3 V				0.89		1.5	0.89		1.5	
			4.5 V	4.5 V				1.51		1.97	1.51		1.97	
			5.5 V	5.5 V				1.88		2.4	1.88		2.4	
		Control Input (DIR) (Referenced to V_{CCA})	1.1 V	1.1 V				0.17		0.48	0.17		0.48	V
			1.4 V	1.4 V				0.28		0.6	0.28		0.6	
			1.65 V	1.65 V				0.35		0.71	0.35		0.71	
			2.3 V	2.3 V				0.56		1	0.56		1	
			3 V	3 V				0.89		1.5	0.89		1.5	
			4.5 V	4.5 V				1.51		2	1.51		2	
			5.5 V	5.5 V				1.88		2.46	1.88		2.46	
ΔV_T	Input-threshold hysteresis ($V_{T+} - V_{T-}$)	Data Inputs (Ax, Bx) (Referenced to V_{CCI})	1.1 V	1.1 V				0.2		0.4	0.2		0.4	V
			1.4 V	1.4 V				0.25		0.5	0.25		0.5	
			1.65 V	1.65 V				0.3		0.55	0.3		0.55	
			2.3 V	2.3 V				0.38		0.65	0.38		0.65	
			3 V	3 V				0.46		0.72	0.46		0.72	
			4.5 V	4.5 V				0.58		0.93	0.58		0.93	
			5.5 V	5.5 V				0.69		1.06	0.69		1.06	
		Control Input (DIR) (Referenced to V_{CCA})	1.1 V	1.1 V				0.2		0.4	0.2		0.4	V
			1.4 V	1.4 V				0.25		0.5	0.25		0.5	
			1.65 V	1.65 V				0.3		0.55	0.3		0.55	
			2.3 V	2.3 V				0.38		0.65	0.38		0.65	
			3 V	3 V				0.46		0.72	0.46		0.72	
			4.5 V	4.5 V				0.58		0.93	0.58		0.93	
			5.5 V	5.5 V				0.69		1.06	0.69		1.06	

Copyright © 2022 Texas Instruments Incorporated

6.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)(1) (2)

PARAMETER		TEST CONDITIONS	V_{CCA}	V_{CCB}	Operating free-air temperature (T_A)									UNIT
					25°C			–40°C to 85°C			–40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{OH}	High-level output voltage (3)	I_{OH} = –100 µA	1.1 V – 5.5 V	1.1 V – 5.5 V				V_{CCO} – 0.1			V_{CCO} – 0.1			V
		I_{OH} = –4 mA	1.4 V	1.4 V				1			1			
		I_{OH} = –8 mA	1.65 V	1.65 V				1.2			1.2			
		I_{OH} = –12 mA	2.3 V	2.3 V				1.9			1.9			
		I_{OH} = –24 mA	3 V	3 V				2.4			2.4			
		I_{OH} = –32 mA	4.5 V	4.5 V				3.8			3.8			
V_{OL}	Low-level output voltage (4)	I_{OL} = 100 µA	1.1 V – 5.5 V	1.1 V – 5.5 V						0.1			0.1	V
		I_{OL} = 4 mA	1.4 V	1.4 V						0.3			0.3	
		I_{OL} = 8 mA	1.65 V	1.65 V						0.45			0.45	
		I_{OL} = 12 mA	2.3 V	2.3 V						0.3			0.3	
		I_{OL} = 24 mA	3 V	3 V						0.55			0.55	
		I_{OL} = 32 mA	4.5 V	4.5 V						0.55			0.55	
I_I	Input leakage current	Control input (DIR) V_I = V_{CCA} or GND	1.1 V – 5.5 V	1.1 V – 5.5 V	–0.1		1	–0.1		2	-0.1		2	µA
		Data Inputs (5) (Ax, Bx) V_I = V_{CCI} or GND	1.1 V – 5.5 V	1.1 V – 5.5 V	–0.3		1	–1		1	–2		2	µA
I_{off}	Partial power down current	A Port or B Port V_I or V_O = 0 V – 5.5 V	0 V	0 V – 5.5 V	–1		1	–2		2	–2.5		2.5	µA
			0 V – 5.5 V	0 V	–1		1	–2		2	–2.5		2.5	
$I_{off-float}$	Floating supply Partial power down current	A Port or B Port V_I or V_O = GND	Floating (6)	0 V – 5.5 V	–1.5		1.5	–2		2	–2.5		2.5	µA
			0 V – 5.5 V	Floating (6)	–1.5		1.5	–2		2	–2.5		2.5	
I_{CCA}	V_{CCA} supply current	V_I = V_{CCI} or GND I_O = 0	1.1 V – 5.5 V	1.1 V – 5.5 V			2			2			4	µA
			0 V	5.5 V	–0.2			–0.5			–1			
			5.5 V	0 V			1			1			2	
		V_I = GND I_O = 0	5.5 V	Floating (6)			1			1			2	
I_{CCB}	V_{CCB} supply current	V_I = V_{CCI} or GND I_O = 0	1.1 V – 5.5 V	1.1 V – 5.5 V			2			2			4	µA
			0 V	5.5 V			1			1			2	
			5.5 V	0 V	–0.2			–0.5			–1			
		V_I = GND I_O = 0	Floating (6)	5.5 V			1			1			2	
I_{CCA} + I_{CCB}	Combined supply current	V_I = V_{CCI} or GND I_O = 0	1.1 V – 5.5 V	1.1 V – 5.5 V			3			4			6	µA

6.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)(1) (2)

PARAMETER		TEST CONDITIONS	V_{CCA}	V_{CCB}	Operating free-air temperature (T_A)									UNIT
					25°C			–40°C to 85°C			–40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
ΔI_{CCA}	V_{CCA} additional supply current per input	Control input (DIR): $V_I = V_{CCA} – 0.6$ V A port = VCCA or GND B Port = open	3.0 V – 5.5 V	3.0 V – 5.5 V					50			75		µA
		A Port: $V_I = V_{CCA} – 0.6$ V DIR = V_{CCA}, B Port = open	3.0 V – 5.5 V	3.0 V – 5.5 V					50			75		
ΔI_{CCB}	V_{CCB} additional supply current per input	B Port: $V_I = V_{CCB}$ - 0.6 V DIR = GND, A Port = open	3.0 V – 5.5 V	3.0 V – 5.5 V					50			75		µA
C_i	Control Input Capacitance	V_I = 3.3 V or GND	3.3 V	3.3 V		2.2			5			5		pF
C_{io}	Data I/O Capacitance	V_{CCO} = 0 V V_O = 1.65 V DC +1 MHz -16 dBm sine wave	3.3 V	3.3 V		4.3			10.5			10.5		pF

(1) V_{CCI} is the V_{CC} associated with the input port.
(2) V_{CCO} is the V_{CC} associated with the output port.
(3) Tested at $V_I = V_{T+(MAX)}$.
(4) Tested at $V_I = V_{T-(MIN)}$.
(5) For I/O ports, the parameter I_I includes the I_{OZ} current.
(6) Floating is defined as a node that is both not actively driven by an external device and has leakage not exeeding 10 nA.

Copyright © 2022 Texas Instruments Incorporated

6.6 Switching Characteristics, V_{CCA} = 1.2 ± 0.1 V

See Figure 7-1 and Table 7-1 for test circuit and loading. See Figure 7-2, Figure 7-3, and Figure 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	6		85	4		41	3		36	1		33	1		34	1		44	ns
				−40°C to 125°C	6		85	4		41	3		36	1		33	1		34	1		44	
		B	A	−40°C to 85°C	6		85	5		71	4		67	3		60	3		57	3		58	
				−40°C to 125°C	6		85	5		71	4		67	3		60	3		57	3		58	
t_{dis}	Disable time	DIR	A	−40°C to 85°C	5		53	5		53	5		53	5		53	5		53	4		53	ns
				−40°C to 125°C	5		53	5		53	5		53	5		53	5		53	4		53	
		DIR	B	−40°C to 85°C	10		85	7		47	6		41	5		34	5		33	4		32	
				−40°C to 125°C	10		85	7		47	6		41	5		34	5		33	4		32	
t_{en}	Enable time	DIR	A	−40°C to 85°C	21		150	17		110	16		99	13		86	13		83	12		85	ns
				−40°C to 125°C	21		150	17		110	16		99	13		86	13		83	12		85	
		DIR	B	−40°C to 85°C	16		118	14		89	13		84	12		81	11		82	11		92	
				−40°C to 125°C	16		118	14		89	13		84	12		81	11		82	11		92	

Copyright © 2022 Texas Instruments Incorporated

6.7 Switching Characteristics, V_{CCA} = 1.5 ± 0.1 V

See Figure 7-1 and Table 7-1 for test circuit and loading. See Figure 7-2, Figure 7-3, and Figure 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})																		UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	5		71	3		29	1		24	1		20	1		19	1		19	ns
				−40°C to 125°C	5		71	3		30	1		25	1		21	1		20	1		20	
		B	A	−40°C to 85°C	4		41	3		29	2		27	1		23	1		22	1		21	
				−40°C to 125°C	4		41	3		30	2		27	1		24	1		22	1		22	
t_{dis}	Disable time	DIR	A	−40°C to 85°C	2		26	2		26	2		26	2		26	2		26	2		26	ns
				−40°C to 125°C	2		27	2		27	2		27	2		27	2		27	2		27	
		DIR	B	−40°C to 85°C	8		71	6		38	5		32	3		25	3		24	2		22	
				−40°C to 125°C	8		71	6		39	5		34	3		26	3		25	2		23	
t_{en}	Enable time	DIR	A	−40°C to 85°C	17		106	13		63	12		54	9		44	9		41	8		39	ns
				−40°C to 125°C	17		106	13		64	12		56	9		45	9		42	8		40	
		DIR	B	−40°C to 85°C	12		90	10		51	9		45	8		40	7		39	7		39	
				−40°C to 125°C	12		90	10		51	9		47	8		42	7		40	7		40	

Copyright © 2022 Texas Instruments Incorporated

6.8 Switching Characteristics, V_{CCA} = 1.8 ± 0.15 V

See Figure 7-1 and Table 7-1 for test circuit and loading. See Figure 7-2, Figure 7-3, and Figure 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	4		67	2		27	1		22	1		18	1		16	1		16	ns
				−40°C to 125°C	4		67	2		27	1		22	1		18	1		17	1		16	
		B	A	−40°C to 85°C	3		36	1		24	1		22	1		19	1		18	1		17	
				−40°C to 125°C	3		36	1		25	1		22	1		19	1		18	1		18	
t_{dis}	Disable time	DIR	A	−40°C to 85°C	2		21	2		21	2		21	2		21	2		21	1		21	ns
				−40°C to 125°C	2		22	2		22	2		22	2		22	2		22	1		22	
		DIR	B	−40°C to 85°C	7		65	5		35	4		29	2		22	2		21	1		19	
				−40°C to 125°C	7		65	5		36	4		30	2		24	2		22	1		20	
t_{en}	Enable time	DIR	A	−40°C to 85°C	15		96	11		54	10		46	8		36	7		34	6		31	ns
				−40°C to 125°C	15		96	11		56	10		48	8		38	7		35	6		33	
		DIR	B	−40°C to 85°C	11		80	9		42	7		37	7		33	6		31	6		30	
				−40°C to 125°C	11		80	9		43	7		39	7		34	6		33	6		32	

Copyright © 2022 Texas Instruments Incorporated

6.9 Switching Characteristics, V_{CCA} = 2.5 ± 0.2 V

See Figure 7-1 and Table 7-1 for test circuit and loading. See Figure 7-2, Figure 7-3, and Figure 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	3		60	1		23	1		19	1		15	1		14	1		13	ns
				−40°C to 125°C	3		60	1		24	1		19	1		15	1		14	1		13	
		B	A	−40°C to 85°C	1		33	1		20	1		18	1		15	1		14	1		14	
				−40°C to 125°C	1		33	1		21	1		18	1		15	1		14	1		14	
t_{dis}	Disable time	DIR	A	−40°C to 85°C	1		15	1		15	1		15	1		15	1		15	1		15	ns
				−40°C to 125°C	1		15	1		15	1		15	1		15	1		15	1		15	
		DIR	B	−40°C to 85°C	5		54	4		30	3		25	2		19	2		18	1		16	
				−40°C to 125°C	5		54	4		31	3		26	2		21	2		19	1		17	
t_{en}	Enable time	DIR	A	−40°C to 85°C	12		82	9		44	8		37	6		29	6		27	5		24	ns
				−40°C to 125°C	12		82	9		45	8		39	6		31	6		29	5		26	
		DIR	B	−40°C to 85°C	8		67	6		33	5		29	4		25	4		23	4		22	
				−40°C to 125°C	8		67	6		34	5		30	4		26	4		24	4		23	

Copyright © 2022 Texas Instruments Incorporated

6.10 Switching Characteristics, V_{CCA} = 3.3 ± 0.3 V

See Figure 7-1 and Table 7-1 for test circuit and loading. See Figure 7-2, Figure 7-3, and Figure 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	3		57	1		22	1		18	1		14	1		13	1		12	ns
				−40°C to 125°C	3		57	1		22	2		18	1		14	1		13	1		12	
		B	A	−40°C to 85°C	1		34	1		19	1		16	1		13	1		13	1		12	
				−40°C to 125°C	1		34	1		20	1		17	1		14	1		13	1		12	
t_{dis}	Disable time	DIR	A	−40°C to 85°C	1		14	1		14	1		14	1		14	1		14	1		14	ns
				−40°C to 125°C	1		14	1		14	1		14	1		14	1		14	1		14	
		DIR	B	−40°C to 85°C	5		49	3		27	3		23	1		18	2		17	1		15	
				−40°C to 125°C	5		49	3		28	3		24	1		19	2		18	1		16	
t_{en}	Enable time	DIR	A	−40°C to 85°C	12		78	8		39	7		33	6		26	5		25	4		22	ns
				−40°C to 125°C	12		78	8		40	7		35	6		28	5		26	4		23	
		DIR	B	−40°C to 85°C	8		64	6		30	5		26	4		23	4		21	4		20	
				−40°C to 125°C	8		64	6		31	5		27	4		24	4		22	4		21	

Copyright © 2022 Texas Instruments Incorporated

6.11 Switching Characteristics, V_{CCA} = 5.0 ± 0.5 V

See Figure 7-1 and Table 7-1 for test circuit and loading. See Figure 7-2, Figure 7-3, and Figure 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	3		58	1		21	1		17	1		14	1		12	1		11	ns
				−40°C to 125°C	3		58	1		22	1		18	1		14	1		13	1		11	
		B	A	−40°C to 85°C	1		44	1		19	1		16	1		13	1		12	1		11	
				−40°C to 125°C	1		44	1		20	1		16	1		13	1		12	1		11	
t_{dis}	Disable time	DIR	A	−40°C to 85°C	1		12	1		12	1		12	1		12	1		12	1		12	ns
				−40°C to 125°C	1		12	1		12	1		12	1		12	1		12	1		12	
		DIR	B	−40°C to 85°C	5		48	3		26	3		21	1		16	2		16	1		14	
				−40°C to 125°C	5		48	3		26	3		22	1		17	2		17	1		15	
t_{en}	Enable time	DIR	A	−40°C to 85°C	11		87	8		38	7		31	5		24	5		22	4		20	ns
				−40°C to 125°C	11		87	8		39	7		32	5		25	5		24	4		21	
		DIR	B	−40°C to 85°C	7		63	5		28	4		24	3		20	3		19	2		18	
				−40°C to 125°C	7		63	5		28	4		25	3		21	3		19	2		18	

Copyright © 2022 Texas Instruments Incorporated

6.12 Switching Characteristics: T_{sk}, T_{MAX}

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V_{CCI}	V_{CCO}	Operating free-air temperature (T_A)			UNIT
					−40°C to 125°C			
					MIN	TYP	MAX	
T_{MAX} - Maximum Data Rate	50% Duty Cycle Input One channel switching 20% of pulse > 0.7*V_{CCO} 20% of pulse < 0.3*V_{CCO}	Up Translation	3.0 V – 3.6 V	4.5 V – 5.5 V	200	420		Mbps
			2.25 V – 2.75 V	4.5 V – 5.5 V	150	300		
			1.65 V – 1.95 V	4.5 V – 5.5 V	100	200		
			1.1 V – 1.3 V	4.5 V – 5.5 V	20	40		
			1.65 V – 1.95 V	3.0 V – 3.6 V	100	210		
			1.1 V – 1.3 V	3.0 V – 3.6 V	10	20		
			1.1 V – 1.3 V	1.65 V – 1.95 V	5	10		
		Down Translation	4.5 V – 5.5 V	3.0 V – 3.6 V	100	210		
			4.5 V – 5.5 V	2.25 V – 2.75 V	75	140		
			4.5 V – 5.5 V	1.65 V – 1.95 V	50	75		
			4.5 V – 5.5 V	1.1 V – 1.3 V	15	30		
			3.0 V – 3.6 V	1.65 V – 1.95 V	40	75		
			3.0 V – 3.6 V	1.1 V – 1.3 V	10	20		
			1.65 V – 1.95 V	1.1 V – 1.3 V	5	10		

6.13 Operating Characteristics

T_A = 25°C (1)

PARAMETER		Test Conditions	Supply Voltage (V_{CCB} = V_{CCA})						UNIT
			1.2 ± 0.1 V	1.5 ± 0.1 V	1.8 ± 0.15 V	2.5 ± 0.2 V	3.3 ± 0.3 V	5.0 ± 0.5 V	
			TYP	TYP	TYP	TYP	TYP	TYP	
C_{pdA} (2)	A to B	A Port CL = 0, RL = Open f = 10 MHz t_{rise} = t_{fall} = 1 ns	3.2	3.4	3.5	3.7	3.9	5.1	pF
	B to A		19.4	19.6	19.8	20.4	21.8	25.7	
C_{pdB} (2)	A to B	B Port CL = 0, RL = Open f = 10 MHz t_{rise} = t_{fall} = 1 ns	19.3	19.5	19.7	20.4	21.6	25.3	pF
	B to A		3.3	3.5	3.6	4.0	4.4	5.0	

(1) For more information about power dissipation capacitance, see the *CMOS Power Consumption and C_{pd} Calculation* application report.
(2) C_{pdA} and C_{pdB} are repectively A-Port and B-Port power dissipation capacitances per transceiver.

Copyright © 2022 Texas Instruments Incorporated

6.14 Typical Characteristics

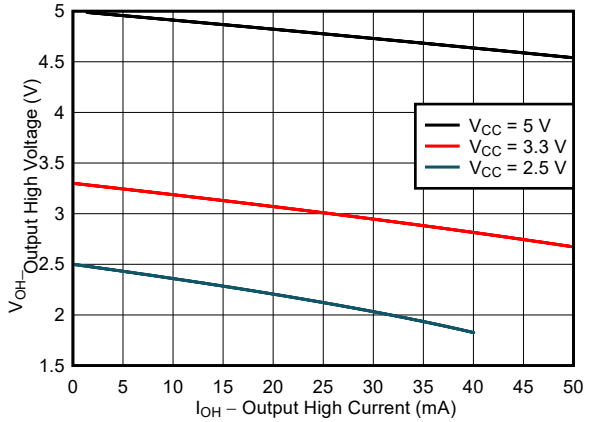


図 6-1. Typical (T_A=25°C) Output High Voltage (V_{OH}) vs Source Current (I_{OH})

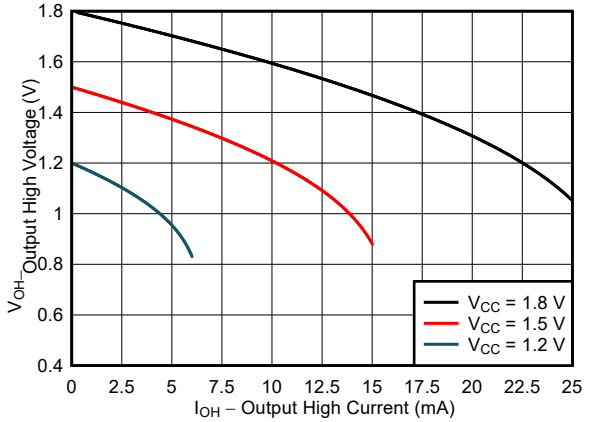


図 6-2. Typical (T_A=25°C) Output High Voltage (V_{OH}) vs Source Current (I_{OH})

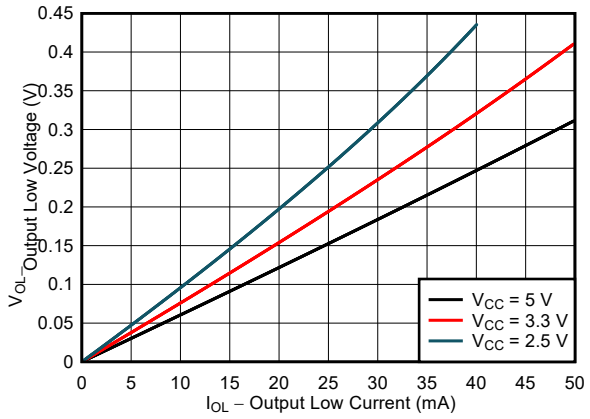


図 6-3. Typical (T_A=25°C) Output High Voltage (V_{OL}) vs Sink Current (I_{OL})

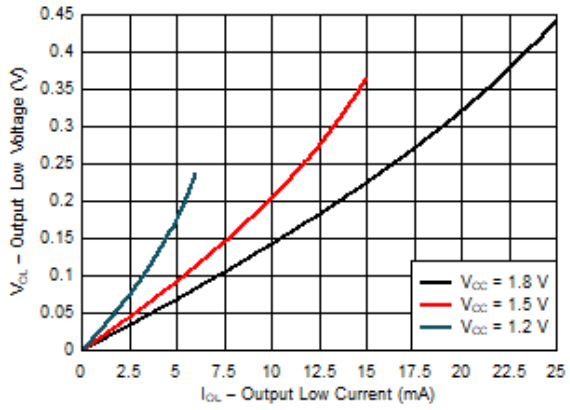


図 6-4. Typical (T_A=25°C) Output High Voltage (V_{OL}) vs Sink Current (I_{OL})

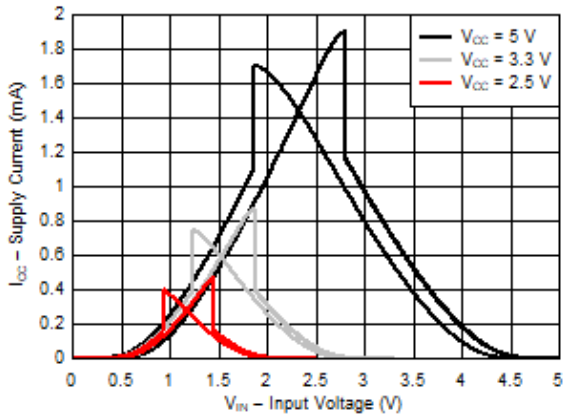


図 6-5. Typical (T_A=25°C) Supply Current (I_{CC}) vs Input Voltage (V_{IN})

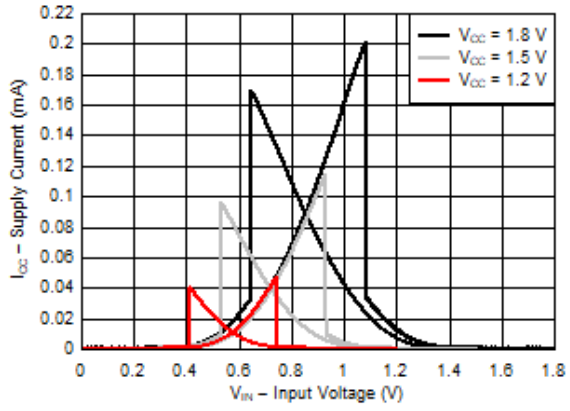


図 6-6. Typical (T_A=25°C) Supply Current (I_{CC}) vs Input Voltage (V_{IN})

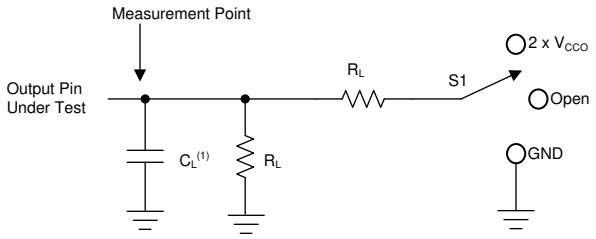
Copyright © 2022 Texas Instruments Incorporated

7 Parameter Measurement Information

7.1 Load Circuit and Voltage Waveforms

Unless otherwise noted, all input pulses are supplied by generators having the following characteristics:

- f = 1 MHz
- Z_O = 50 Ω
- Δt/ΔV ≤ 1 ns/V

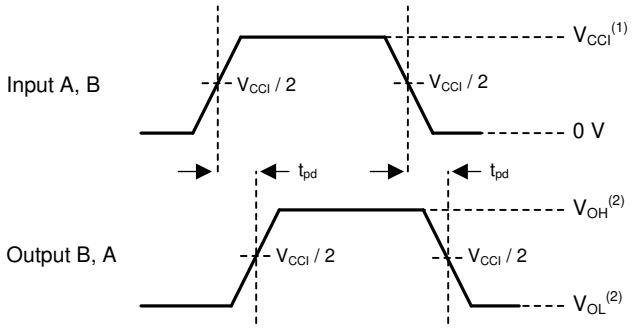


1. C_L includes probe and jig capacitance.

図 7-1. Load Circuit

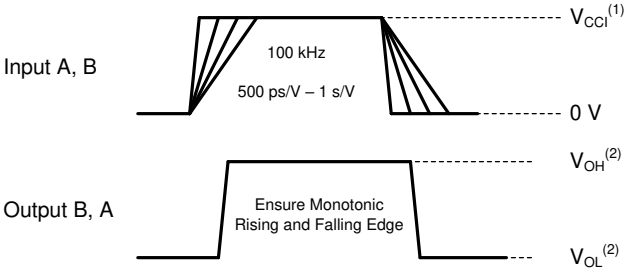
表 7-1. Load Circuit Conditions

Parameter		V_{CCO}	R_L	C_L	S_1	V_{TP}
t_{pd}	Propagation (delay) time	1.1 V – 5.5 V	2 kΩ	15 pF	Open	N/A
t_{en}, t_{dis}	Enable time, disable time	1.1 V – 1.6 V	2 kΩ	15 pF	2 × V_{CCO}	0.1 V
		1.65 V – 2.7 V	2 kΩ	15 pF	2 × V_{CCO}	0.15 V
		3.0 V – 5.5 V	2 kΩ	15 pF	2 × V_{CCO}	0.3 V
t_{en}, t_{dis}	Enable time, disable time	1.1 V – 1.6 V	2 kΩ	15 pF	GND	0.1 V
		1.65 V – 2.7 V	2 kΩ	15 pF	GND	0.15 V
		3.0 V – 5.5 V	2 kΩ	15 pF	GND	0.3 V



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L, C_L, and S_1

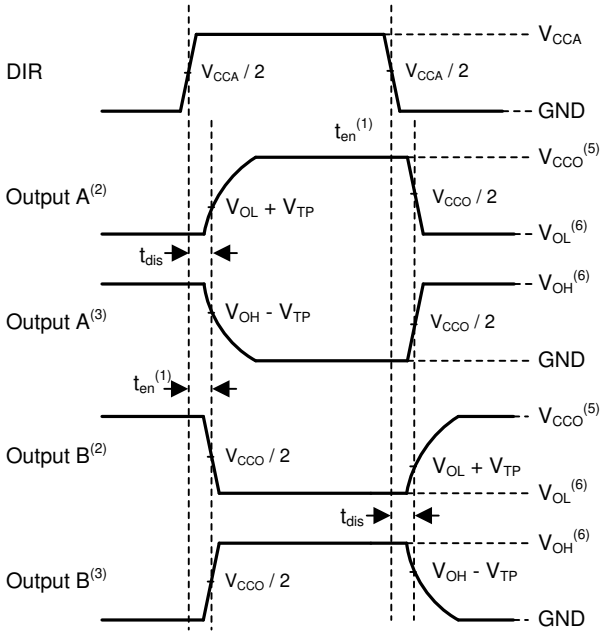
図 7-2. Propagation Delay



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L, C_L, and S_1

図 7-3. Input Transition Rise and Fall Rate

Copyright © 2022 Texas Instruments Incorporated



1. Illustrative purposes only. Enable time is a calculation as described in *Enable Times.*
2. Output waveform on the condition that input is driven to a valid Logic low.
3. Output waveform on the condition that input is driven to a valid Logic high.
4. V_{CCI} is the supply pin associated with the input port.
5. V_{CCO} is the supply pin associated with the output port.
6. V_{OH} and V_{OL} are typical output voltage levels with specified R_L, C_L, and S_1.

図 7-4. Enable Time And Disable Time

Copyright © 2022 Texas Instruments Incorporated

8 Detailed Description

8.1 Overview

The SN74LXC1T45-Q1 is a 1-bit translating transceiver that uses two individually configurable power-supply rails. The device is operational with both V_{CCA} and V_{CCB} supplies as low as 1.1 V and as high as 5.5 V. Additionally, the device can be operated with $V_{CCA} = V_{CCB}$. The A port is designed to track V_{CCA}, and the B port is designed to track V_{CCB}.

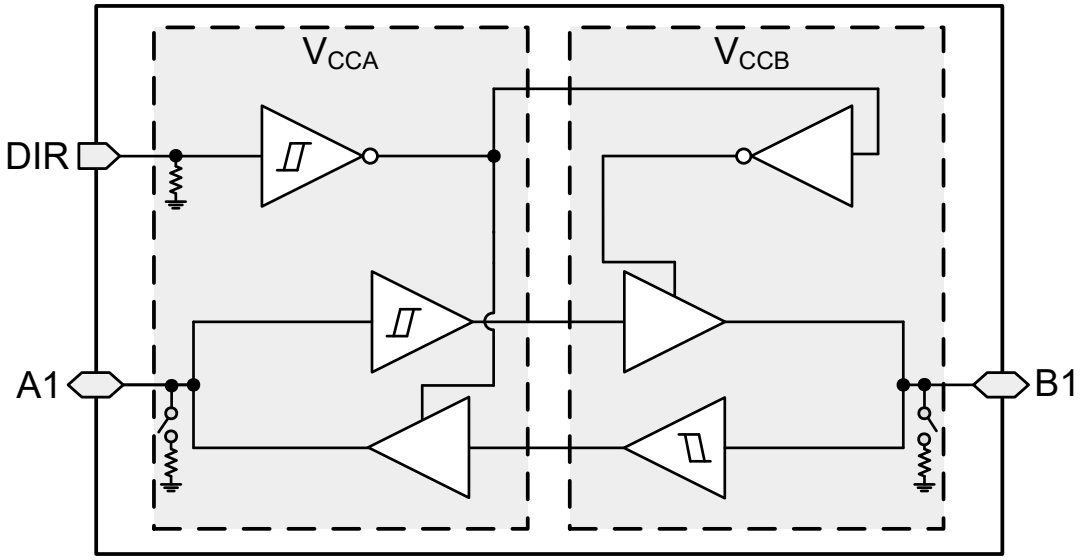
The SN74LXC1T45-Q1 device is designed for asynchronous communication between devices and transmits data from A to B or from B to A based on the logic level of the direction-control input (DIR). The control pins of the SN74LXC1T45-Q1 (DIR) is referenced to V_{CCA}. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess ICC and ICCZ.

This device is fully specified for partial-power-down applications using the I_{off} current. The I_{off} protection circuitry ensures that no excessive current is drawn from or sourced into an input, output, or I/O while the device is powered down.

The V_{CC} isolation or V_{CC} disconnect feature ensures that if either V_{CC} is less than 100 mV or disconnected with the complementary supply within the recommended operating conditions, then both I/O ports are weakly pulled-down and then set to the high-impedance state by disabling their outputs while the supply current is maintained. The $I_{off-float}$ circuitry ensures that no excessive current is drawn from or sourced into an input, output, or I/O while the supply is floating.

Glitch-free power supply sequencing allows either supply rail to be powered on or off in any order while providing robust power sequencing performance.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 CMOS Schmitt-Trigger Inputs with Integrated Pulldowns

Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using ohm's law (R = V ÷ I).

The Schmitt-trigger input architecture provides hysteresis as defined by ΔV_T in the *Electrical Characteristics*, which makes this device extremely tolerant to slow or noisy inputs. Driving the inputs slowly will increase dynamic current consumption of the device. For additional information regarding Schmitt-trigger inputs, see *Understanding Schmitt Triggers*.

Copyright © 2022 Texas Instruments Incorporated

8.3.1.1 I/O's with Integrated Dynamic Pull-Down Resistors

Input circuits of the data I/O's are always active even when the device is disabled. It is recommended to keep a valid voltage level at the I/O's to avoid high current consumption. To help avoid floating inputs on the I/O's during disabling, this device has 100-kΩ typical integrated weak dynamic pull-downs on all data I/O's. When the device is disabled, the dynamic pull-downs are activated for only a short period of time to help drive and keep low any floating inputs before the device I/O's become high impedance. If the I/O lines are floated after the device is disabled, then it is recommended to keep them at a valid input voltage level using the external pull-downs. This feature is ideal for loads of 30 pF or less. If greater capactive loading is present, then external pull-downs are recommended. If an external pull-up is required, then it should be no larger than 15 kΩ to avoid contention with the 100 kΩ internal pull-down.

8.3.1.2 Control Inputs with Integrated Static Pull-Down Resistors

Similar to the data I/O's, a floating control input can cause high current consumption. To help avoid this concern, this device has integrated weak static pull-downs of 5-MΩ typical on the control input (DIR). These pull-downs are always present. For example, if the DIR pin is left floating, then the B port will be configured as an input and the A port configured as an output.

8.3.2 Balanced High-Drive CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The high drive capability of this device creates fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

8.3.3 Partial Power Down (I_{off})

The inputs and outputs for this device enter a high-impedance state when the device is powered down, inhibiting current backflow into the device. The maximum leakage into or out of any input or output pin on the device is specified by I_{off} in the *Electrical Characteristics*.

8.3.4 V_{CC} Isolation and V_{CC} Disconnect ($I_{off\text{-}float}$)

This device has *I/O's with Integrated Dynamic Pull-Down Resistors*. The I/O's will get pulled down and then enter a high-impedance state when either supply is < 100 mV or left floating (disconnected), while the other supply is still connected to the device. It is recommended that the I/O's for this device are not driven and kept at a logic low state prior to floating (disconnecting) either supply.

The maximum supply current is specified by I_{CCx}, while V_{CCx} is floating, in the *Electrical Characteristics*. The maximum leakage into or out of any input or output pin on the device is specified by $I_{off(float)}$ in the *Electrical Characteristics*.

Copyright © 2022 Texas Instruments Incorporated

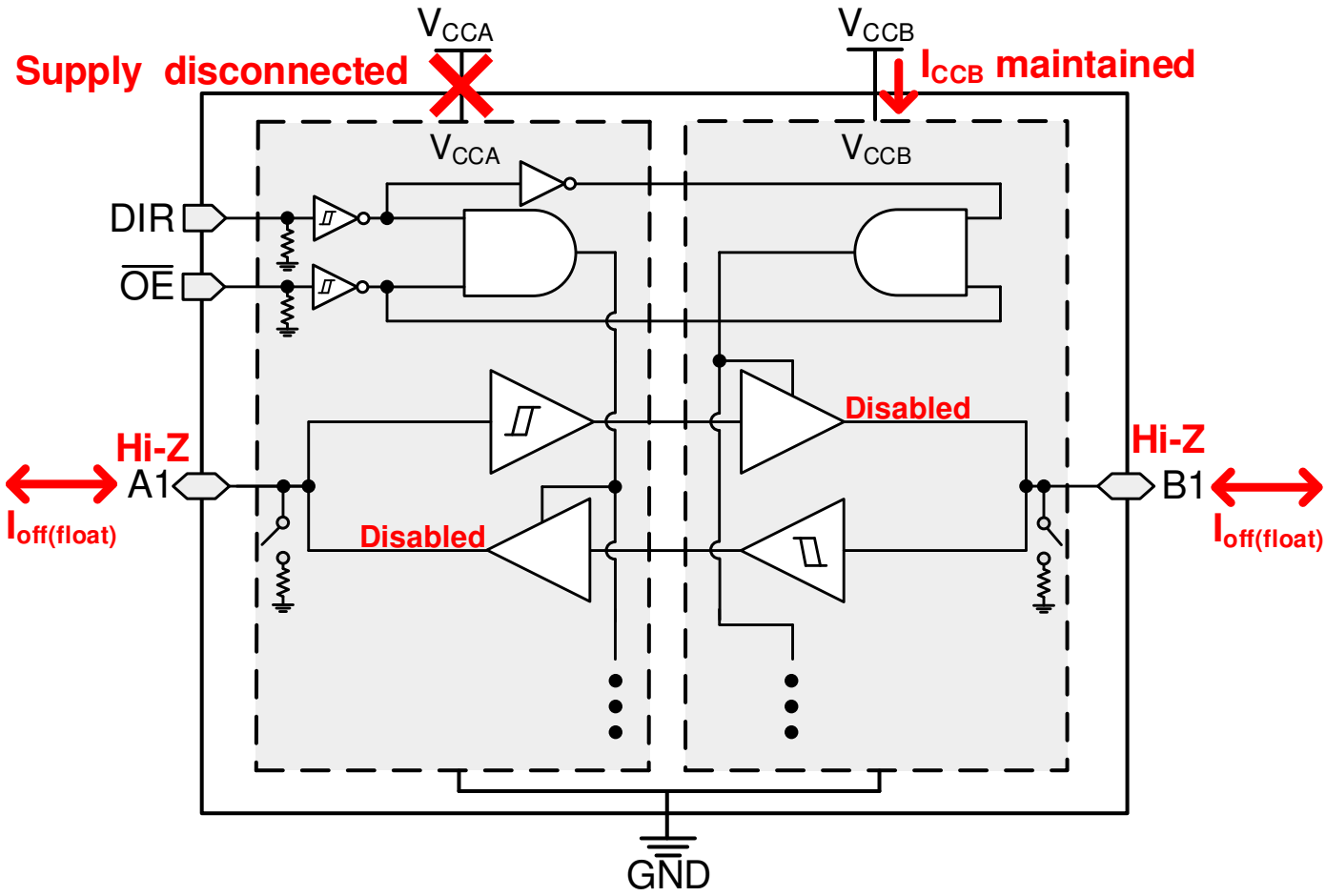


図 8-1. V_{CC} Disconnect Feature

8.3.5 Over-Voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage so long as they remain below the maximum input voltage value specified in the *Recommended Operating Conditions*.

8.3.6 Glitch-Free Power Supply Sequencing

Either supply rail may be powered on or off in any order without producing a glitch on the I/Os (that is, where the output erroneously transitions to VCC when it should be held low or vice versa). Glitches of this nature can be misinterpreted by a peripheral as a valid data bit, which could trigger a false device reset of the peripheral, a false device configuration of the peripheral, or even a false data initialization by the peripheral.

Copyright © 2022 Texas Instruments Incorporated

8.3.7 Negative Clamping Diodes

図 8-2 shows the inputs and outputs to this device that have negative clamping diodes.

> **注意**
>
> Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input negative voltage and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.

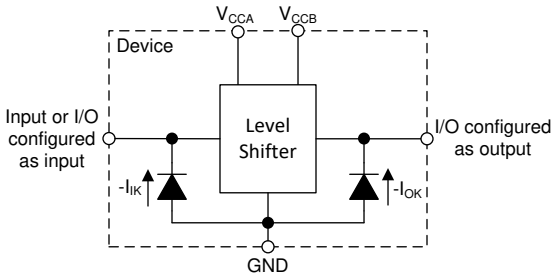


図 8-2. Electrical Placement of Clamping Diodes for Each Input and Output

8.3.8 Fully Configurable Dual-Rail Design

Both the V_{CCA} and V_{CCB} pins can be supplied at any voltage from 1.1 V to 5.5 V, making the device suitable for translating between any of the voltage nodes (1.2 V, 1.5 V, 1.8 V, 3.3 V, and 5.0 V).

8.3.9 Supports High-Speed Translation

The SN74LXC1T45-Q1 device can support high data rate applications. The translated signal data rate can be up to 420 Mbps when the signal is translated from 3.3 V to 5.0 V.

8.4 Device Functional Modes

表 8-1. Function Table

CONTROL INPUTS (1)	PORT STATUS		OPERATION
DIR	A PORT	B PORT	
L	Output (Enabled)	Input (Hi-Z)	B data to A bus
H	Input (Hi-Z)	Output (Enabled)	A data to B bus

(1) Input circuits of the data I/Os are always active and should be kept at a valid logic level.

Copyright © 2022 Texas Instruments Incorporated

9 Application and Implementation

注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

9.1 Application Information

The SN74LXC1T45-Q1 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The SN74LXC1T45-Q1 device is ideal for use in applications where a push-pull driver is connected to the data I/O. The maximum data rate can be up to 420 Mbps when the device translates a signal from 3.3 V to 5.0 V.

9.2 Enable Times

Calculate the enable times for the SN74LXC1T45-Q1 using the following formulas:

$$t_{A_en}\ (\text{DIR to A}) = t_{dis}\ (\text{DIR to B}) + t_{pd}\ (\text{B to A}) \quad (1)$$

$$t_{B_en}\ (\text{DIR to B}) = t_{dis}\ (\text{DIR to A}) + t_{pd}\ (\text{A to B}) \quad (2)$$

In a bidirectional application, these enable times provide the maximum delay time from the time the DIR bit is switched until an output is expected. For example, if the SN74LXC1T45-Q1 initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled (t_{dis}) before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay (t_{pd}). To avoid bus contention, care should be taken to not apply an input signal prior to the output being disabled (t_{dis} maximum).

9.3 Typical Application

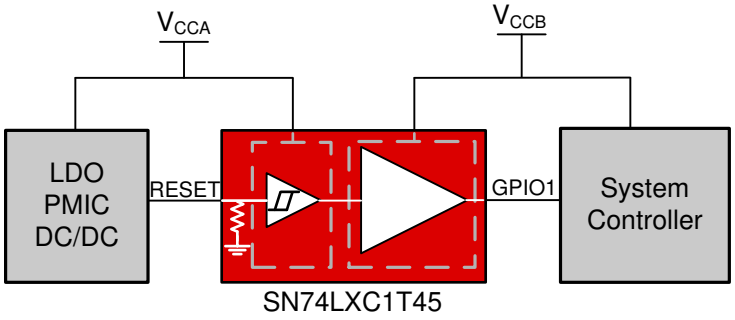


図 9-1. LED Driver Application

9.3.1 Design Requirements

For this design example, use the parameters listed in 表 9-1.

表 9-1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUES
Input voltage range	1.1 V to 5.5 V
Output voltage range	1.1 V to 5.5 V

9.3.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the SN74LXC1T45-Q1 device to determine the input voltage range. For a valid logic-high, the value must exceed the positive-going input-threshold voltage (V_{t+}) of the input port. For a valid logic low the value must be less than the negative-going input-threshold voltage (V_{t-}) of the input port.
- Output voltage range
  - Use the supply voltage of the device that the SN74LXC1T45-Q1 device is driving to determine the output voltage range.

10 Power Supply Recommendations

Always apply a ground reference to the GND pins first. This device is designed for glitch free power sequencing without any supply sequencing requirements such as ramp order or ramp rate.

This device was designed with various power supply sequencing methods in mind to help prevent unintended triggering of downstream devices, as described in *Glitch-free Power Supply Sequencing*.

11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, the following common printed-circuit board layout guidelines are recommended:

- Use bypass capacitors on the power supply pins and place them as close to the device as possible. A 0.1 µF capacitor is recommended, but transient performance can be improved by having both 1 µF and 0.1 µF capacitors in parallel as bypass capacitors.
- The high drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing.

11.2 Layout Example

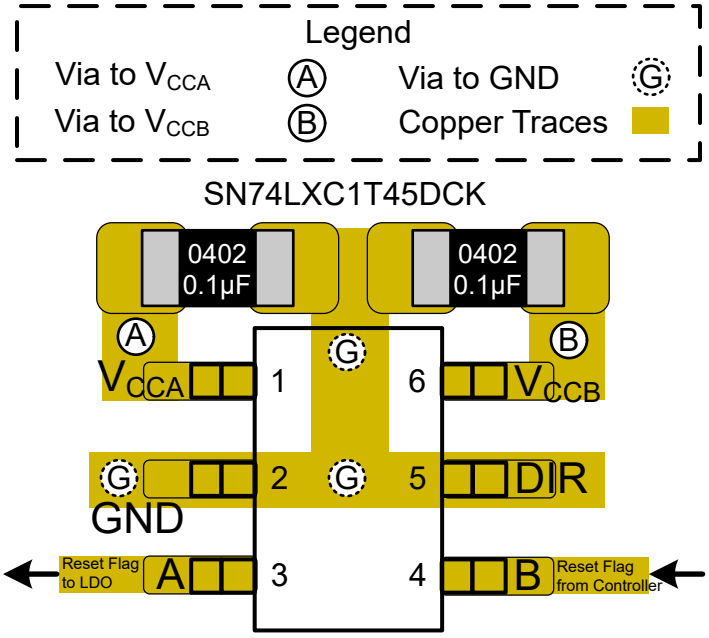


図 11-1. Layout Example − SN74LXC1T45-Q1

Copyright © 2022 Texas Instruments Incorporated

12 Device and Documentation Support

12.1 Device Support

12.1.1 Regulatory Requirements

No statutory or regulatory requirements apply to this device.

There are no special characteristics for this product.

12.2 Documentation Support

12.2.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *Understanding Schmitt Triggers* application report

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 サポート・リソース

TI E2E™ サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計で必要な支援を迅速に得ることができます。

リンクされているコンテンツは、該当する貢献者により、現状のまま提供されるものです。これらは TI の仕様を構成するものではなく、必ずしも TI の見解を反映したものではありません。TI の使用条件を参照してください。

12.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.
すべての商標は、それぞれの所有者に帰属します。

12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

TI Glossary — This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Copyright © 2022 Texas Instruments Incorporated

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LXC1T45QDCKRQ1	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	2NMT
SN74LXC1T45QDCKRQ1.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2NMT
SN74LXC1T45QDRYRQ1	Active	Production	SON (DRY) | 6	5000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MI
SN74LXC1T45QDRYRQ1.A	Active	Production	SON (DRY) | 6	5000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MI

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LXC1T45-Q1 :

- Catalog : SN74LXC1T45

NOTE: Qualified Version Definitions:

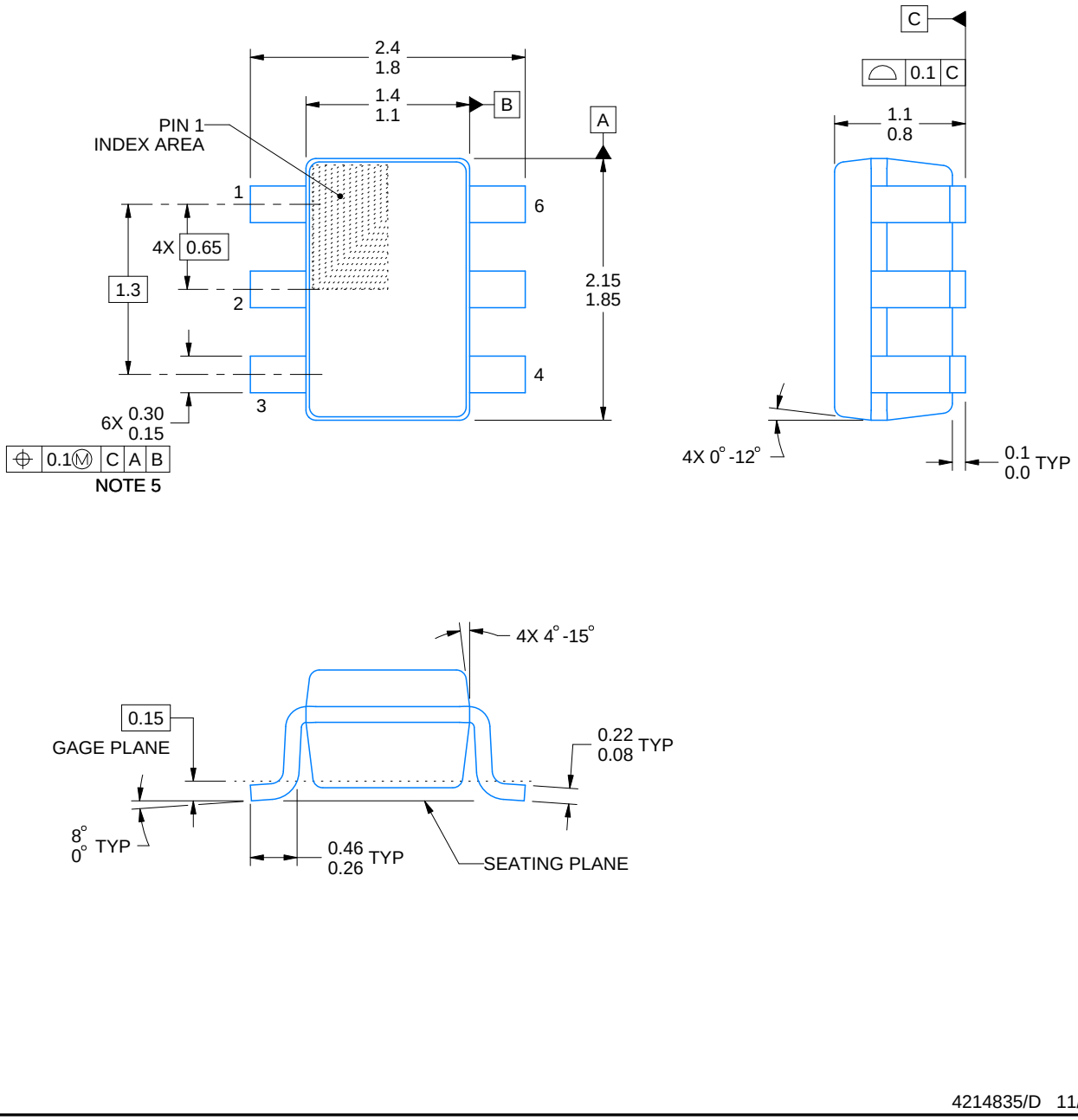
- Catalog - TI's standard catalog product

PACKAGE OUTLINE

DCK0006A

SOT - 1.1 max height

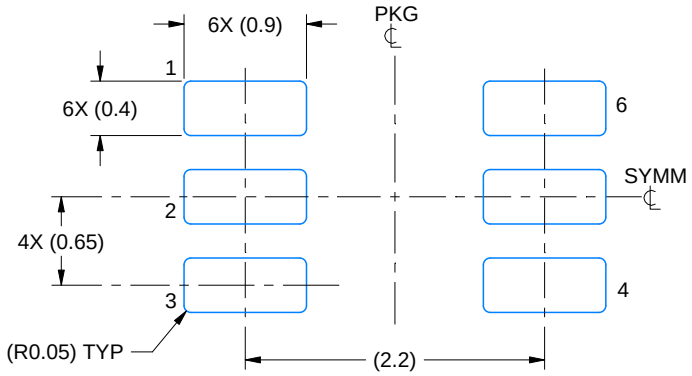
SMALL OUTLINE TRANSISTOR



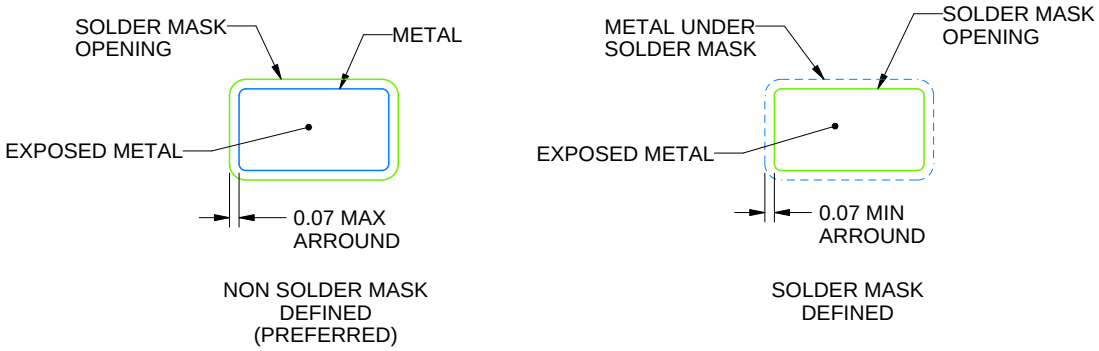
4214835/D 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

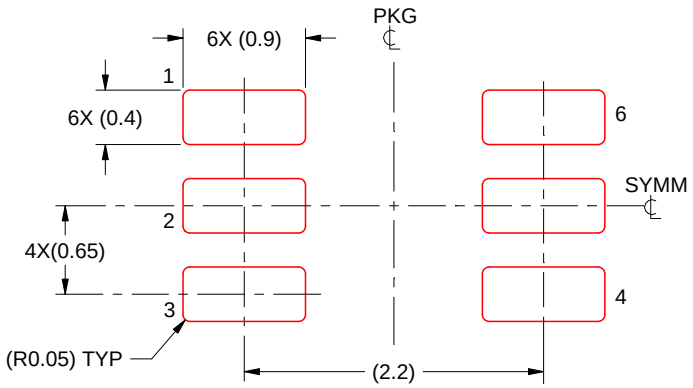


SOLDER MASK DETAILS

4214835/D 11/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

DRY 6 USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



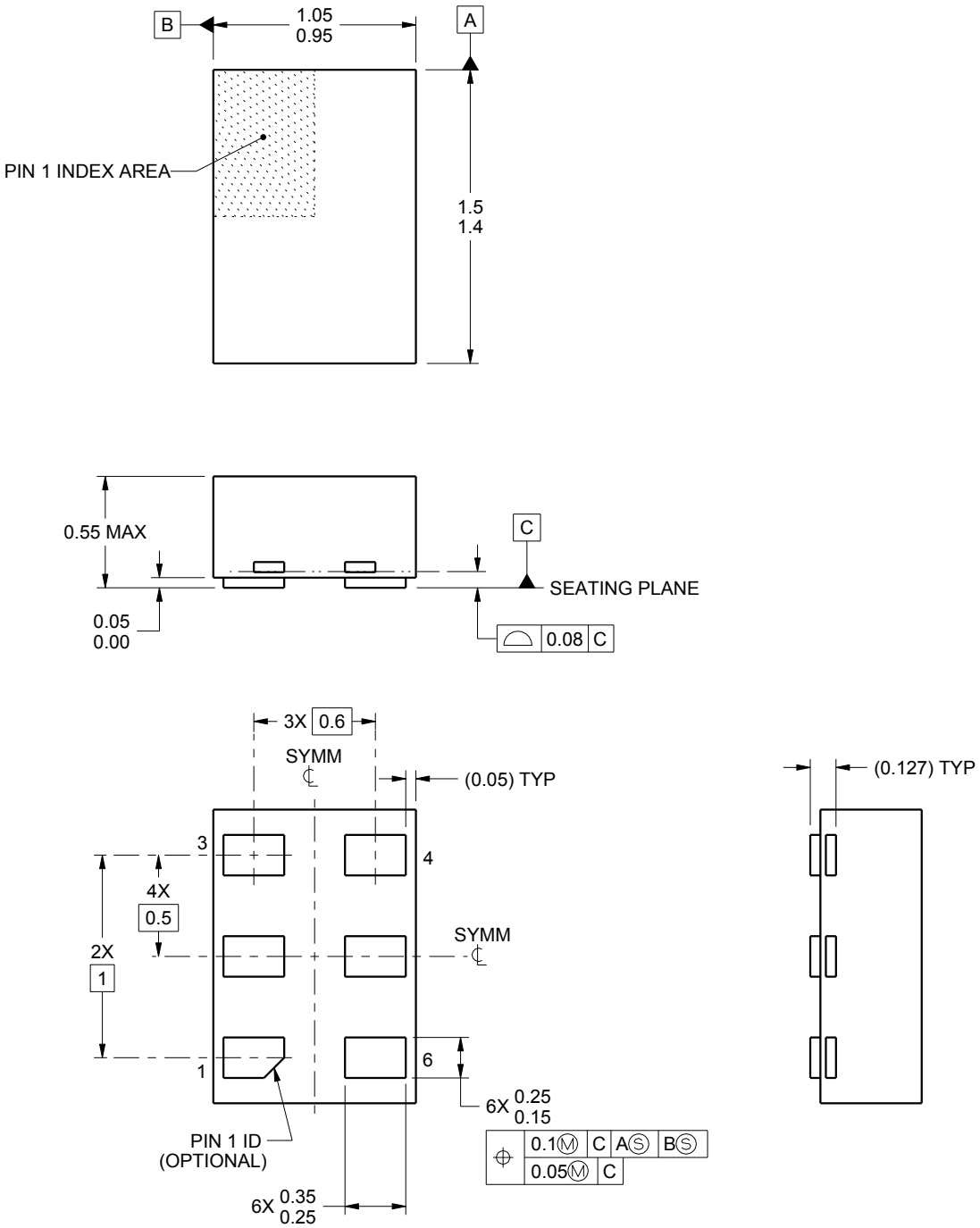
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

PACKAGE OUTLINE

DRY0006B

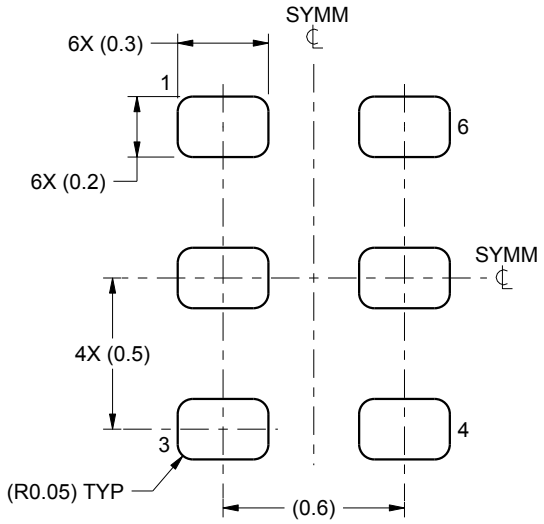
USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

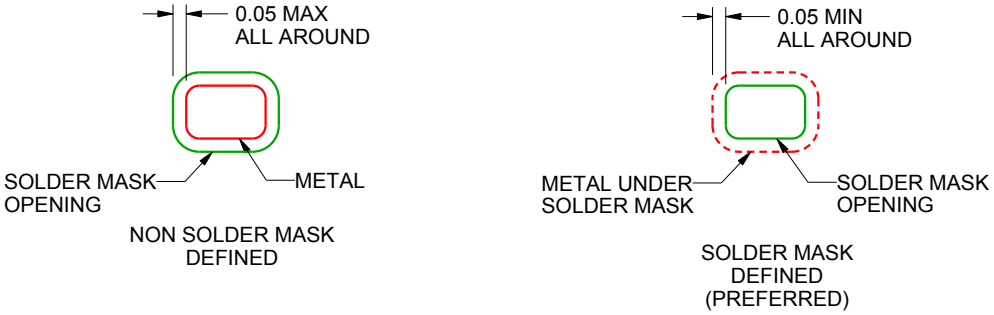


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
1:1 RATIO WITH PKG SOLDER PADS
SCALE:40X



SOLDER MASK DETAILS

4222207/B 02/2016

NOTES: (continued)

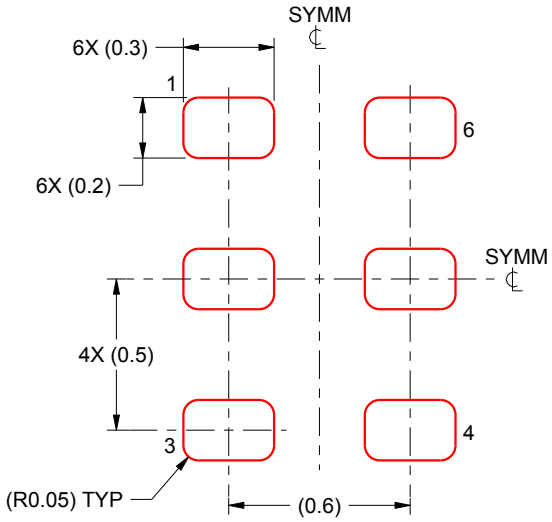
3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

DRY0006B

USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1 mm THICK STENCIL
SCALE:40X

4222207/B 02/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

重要なお知らせと免責事項

TI は、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、TI 製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した TI 製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている TI 製品を使用するアプリケーションの開発の目的でのみ、TI はその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。TI や第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、TI およびその代理人を完全に補償するものとし、TI は一切の責任を拒否します。

TI の製品は、 TI の販売条件 、 TI の総合的な品質ガイドライン 、 ti.com または TI 製品などに関連して提供される他の適用条件に従い提供されます。TI がこれらのリソースを提供することは、適用される TI の保証または他の保証の放棄の拡大や変更を意味するものではありません。 TI がカスタム、またはカスタマー仕様として明示的に指定していない限り、TI の製品は標準的なカタログに掲載される汎用機器です。

お客様がいかなる追加条項または代替条項を提案する場合も、TI はそれらに異議を唱え、拒否します。

Copyright © 2026, Texas Instruments Incorporated

最終更新日：2025 年 10 月